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Universal AC Input, 5.3 V 2 A Output, 10.6 W Charger Using NCP1360



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DESIGN NOTE

Table 1. DEVICE DETAILS								
Device	Application	Input Voltage	Output Power	Topology	I/O Isolation			
NCP1360BBCC NCP1360BCCC	Mobile, Tablet, Charger, Adapter	90 to 264 Vac	10.6 W	Quasi Resonant Flyback	Yes			

Item	Output Specification	Test Condition		
Rated Input Voltage	100 ~ 240 Vac	_		
Input Voltage Range	90 ~ 264 Vac	-		
Input Frequency Range	47 ~ 63 Hz	-		
Inrush Current	< 30 A	264 Vac and 2 A Load		
Average Efficiency	> 82%	Measured at Board End		
Average Efficiency at Cable End	> 78%	Measured at Cable End		
Standby Power	< 50 mW & 75 mW	90 ~ 264 Vac		
Output Voltage	5 ~ 5.5 V, 5.3 V at 2 A	90 ~ 264 Vac and 0 ~ 2 A		
Output Current	2 A	90 ~ 264 Vac		
Rated Output Power	> 10.6 W	90 ~ 264 Vac		
Ripple and Noise	< 120 mV	90 ~ 264 Vac, 1 μF + 0.1 μF CAP@E-load		
Rise Time	< 30 ms	At No/Full Load, 115 Vac & 230 Vac		
Start-up Time	< 1 .5 s	90 ~ 264 Vac and 0 ~ 2 A		
Over Shoot	< 6.4 V	At 1 m USB Cable End		
Transient Response	4.5 ~ 5.5 V	0.1–1.9 A, 0.25 A/µs, 10 ms Cycle		

Circuit Description

This design note describes a 10.6 W, universal AC input, isolated Quasi-Resonant flyback converter for smart phone, tablet charger and smart socket power supply etc.

The featured power supply is a primary side constant voltage and current regulation utilizing ON Semiconductor's new NCP1360 current mode controller which is in TSOP–6 package. This design note provides the complete circuit schematic details, layout, test data and BOM for 5.3 V, 2 A power supply.

Both NCP1360BBCC and NCP1360BCCC are all tested in this design, it has almost same performance except standby power and dynamic response. 1. Input Circuit:

Rectifier, filter and EMC circuit formed by D1, C1, C1, L1, NTC is 2.5 Ω negative temperature coefficient resistor to provide inrush protection, FR1 provides short-circuit protection when large AC input current occurs.

 NCP1360 Control Circuit: R8 and R9 consists of voltage simple network to set output voltage, C12 is a delayed capacitor to delay switching on to valley.

R12 and R13 is a current sensing resistor to decide how much current can be set, R10 and CS pin parasitic capacitor consists of a filter to filter current spike. R19, C11 and C9 consist of a type II compensation network to provide voltage feedback

control loop compensation.

R5 and R11 is start-up resistor, two 7.5 M Ω are used in series to reduce power loss, R4, D6 and C4 consist of V_{CC} supply circuit, R4 can adjust V_{CC} voltage and also prevent D6 from an inrush current. An RCD–R clamp consisting of D5, R3, R6, and C7 limits drain voltage spikes caused by leakage inductance, resistor R6 has a relatively large value to prevent any excessive ringing on the drain voltage waveform and R3 can limit the reverse recovery current through D5.

3. Output Rectification and Filter: The transformer (T1) secondary is rectified by D2, a Schottky barrier-type diode (chosen for higher efficiency), and filtered by C3, C5 and C8. In this application, C3 and C5 have sufficiently low ESR characteristics to allow meeting the output voltage ripple requirement without adding an LC post filter. C6 and R7 are snubber network of D2 to eliminate excessive ringing on secondary voltage waveform. R14 is a dummy load to prevent output voltage rising at no load.

Key Features

- Primary Side Regulation (PSR) CC/CV Control
- Quasi-Resonant Current Mode Control with Valley Switching
- Valley Lockout Avoids Audible Noise at Valley Jumping Operation
- Built in 4 ms Soft Start
- 110 kHz Maximum Clamp Frequency Operation
- Adjustable Voltage Control Loop Compensation
- 300 mV Cable Drop Compensation
- Wide Operation V_{CC} Range (Up to 30 V)
- Cycle by Cycle Current Limit
- Support External 1500 µF Capacitive Load Start-up
- Built in V_{CC} OVP (Typical 26 V)
- Built in Output UVP in CC Mode (3 V ±6.7%)
- Output OCP, SCP, OVP and Controller OTP Function
- CS Pin Open and Short Protection
- Vs Pin Open and Short Protection
- Meet COC V5 Tier 2
- 100 pF Y Capacitor
- "Travel Adapter" (TA) Form Factor
- Size: $47 \times 34 \times 15$ mm

PCB Layout





Demoboard Photo





Figure 2. Demoboard Photo

Circuit Schematic





Standby Power for NCP1360BBCC at No Load



Figure 4. Standby Power for NCP1360BBCC at No Load



Standby Power for NCP1360BCCC at No Load

Figure 5. Standby Power for NCP1360BCCC at No Load





Figure 6. Average Efficiency between 25%, 50%, 75% and 100% Load



Efficiency vs. Load Curves







Figure 8. I-V Curves

OUTPUT RIPPLE VOLTAGE

(Test Condition: Tested at E-load with 1 m Cable, 1 μF E-CAP and 0.1 μF Ceramic in Parallel)



Figure 9. 90 Vac and 2 A Load

TekS







Figure 11. 230 Vac and 0.5 A Load





TRANSIENT RESPONSE FOR NCP1360BBCC

Figure 13. Test Conditions: 0.2–1.8 A, 250 mA/µs, 10 ms Cycle, 115 Vac



Figure 14. Test Conditions: 0.1–1.9 A, 250 mA/μs, 10 ms Cycle, 115 Vac

TRANSIENT RESPONSE FOR NCP1360BCCC







Figure 17. Test Conditions: 0.2–1.8 A, 250 mA/μs, 10 ms Cycle, 115 Vac



Figure 16. Test Conditions: 50 mA–2 A, 250 mA/µs, 10 ms Cycle, 115 Vac



Figure 18. Test Conditions: 0.1–1.9 A, 250 mA/μs, 10 ms Cycle, 115 Vac



Figure 19. Test Conditions: 264 Vac, No Dummy Load

OVP AND SCP



Figure 20. Test Conditions: SC at Board End

START-UP TIME

OUTPUT VOLTAGE RISE TIME



Figure 21. 90 Vac and 2 A CC Load



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Figure 23. 115 Vac and 2 A CC Load



Figure 24. 230 Vac and 2 A CC Load



OUTPUT VOLTAGE OVERSHOOT





Figure 26. 115 Vac and 2 A CC Load

EXTERNAL 1500 μF CAPACITIVE LOAD START-UP



Figure 27. Test Conditions:Ext. 1500 µF capacitor, 2 A CC Load with 1 V Von Voltage Set, 90 Vac



Figure 28. Startup at 264 Vac and 2 A CC Load



MOSFET DRAIN VOLTAGE

Figure 29. Working at 264 Vac and 2 A CC Load



INRUSH CURRENT

Figure 30. 264 Vac and 2 A CC Load

SECONDARY DIODE REVERSE VOLTAGE



Figure 31. 264 Vac and 2 A CC Load

Bill of Material

Table 2. BILL OF MATERIAL

Items	Qty	Reference	Туре	Part Number	Manufacturer	Value	Package	Description
1	1	C8	Ceramic	Std	Std	0.1 μ F , 50 V	603	Capacitor, Ceramic, 10%
2	1	C6	Ceramic	Std	Std	1000 pF, 50 V	603	Capacitor, Ceramic, 10%
3	1	C9	Ceramic	Std	Std	100 pF, 50 V	603	Capacitor, Ceramic, Chip, 10%
4	1	C10	Ceramic Capacitor	CS65-B2GA101KYNKA	TDK	100 pF, Y1	Lead Type	HV Ceramic Capacitor, Safety Standard Approved, 10%
5	1	C12	Ceramic	Std	Std	10 pF, 50 V	603	Capacitor, Ceramic, Chip, 10%
6	1	C4	Ceramic	C2012X7R1E105K	TDK	1 μF, 35 V	805	Capacitor, Ceramic, Chip, 10%
7	1	C11	Ceramic	Std	Std	33 nF, 50 V	603	Capacitor, Ceramic, Chip, 10%
8	1	C7	Ceramic Capacitor	C3216C0G2J391J	TDK	390 pF, 630 V	1206	Capacitor, Ceramic, Chip, 5%
9	1	D1	Bridge Rectifier	LMB6S	FSC/Others	1 A, 600 V	Micro-DIP	Bridge Rectifier, 600 V, 1 A
10	1	D2	Schottky Rectifier	MBR2045MFS/FERD30S50	ON/ST	20 A, 45 V	SO8FL	Schottky Rectifier, 20 A, 4 5V/ 30 A, 50 V
11	1	D5	Standard Rectifier	DFLR1600	Diodes	1 A, 600 V	POWERDI123	Standard Rectifier, 1 A, 600 V
12	2	D4, D6	Switching Diode	BAS20HT1G	ON Semiconductor	0.2 A, 200 V	SOD323	Switching Diode, SMD
13	1	T1	Transformer	El16/12/8	Customized Transformer		ТН Туре	Core: El16/12/8, Customized Bobbin, 10-pin
14	1	FR1	Micro Fuse	20T–016H	HollyFUSE	1.6 A, 250 Vac	Radial Lead	Micro Fuse, 1.6 A/250 Vac, Radial Lead
15	1	U1	PSR Controller	NCP1360BBCC/BCCC	ON Semiconductor		TSOP-6	PSR Controller without HV Start-up Source, TSOP-6
16	1	Q1	NMOSFET	SW6N70	SAMWIN	6 A, 700 V	IPAK	NMOS, 6 A, 700 V, IPAK
17	1	NTC	NTC	SPNL07D2R5MBI	Sunlord	2.5 Ω	Lead Type	NTC, 2.5 Ω, 3 A

Items	Qty	Reference	Туре	Part Number	Manufacturer	Value	Package	Description
18	1	L1	Fixed Inductor	7447462221	Wurth	220 μH	Lead Type	Axial Leaded Fixed Inductor
19	1	R8	Resistor	Std	Std	100 kΩ	805	Resistor, Chip, 1/5 W, 1%
20	1	R10	Resistor	Std	Std	1 kΩ	603	Resistor, Chip, 1/8 W, 1%
21	1	R9	Resistor	Std	Std	30.9 kΩ	603	Resistor, Chip, 1/8 W, 1%
22	1	R4	Resistor	Std	Std	4.7 Ω	603	Resistor, Chip, 1/8 W, 1%
23	1	R15	Resistor	Std	Std	47 Ω	603	Resistor, Chip, 1/8 W, 1%
24	1	R19	Resistor	Std	Std	82 kΩ	603	Resistor, Chip, 1/8 W, 1%
25	1	R2	Resistor	Std	Std	NA	603	Resistor, Chip, 1/8 W, 1%,
26	1	R12	Resistor	Std	Std	1.6 Ω	805	Resistor, Chip, 1/5 W, 1%
27	1	R13	Resistor	Std	Std	1.8 Ω	805	Resistor, Chip, 1/5 W, 1%
28	1	R3	Resistor	Std	Std	150 Ω	1206	Resistor, Chip, 1/4 W, 1%
29	1	R7	Resistor	Std	Std	20 Ω	805	Resistor, Chip, 1/5 W, 1%
30	1	R6	Resistor	Std	Std	330 kΩ	1206	Resistor, Chip, 1/4 W, 1%
31	1	R14	Resistor	Std	Std	1.6 kΩ @ 600 Hz, 800 Ω @ 1.2 kHz	603	Resistor, Chip, 1/8 W, 1%
32	1	R18	Resistor	Std	Std	1 MΩ	603	Resistor, Chip, 1/8 W, 1%
33	2	R5 R11	Resistor	Std	Std	7.5 MΩ	1206	Resistor, Chip, 1/4 W, 1%
34	2	C1–2	Electrolytic Capacitor	AX/KSH106M400T1Z5H1CK	Rubycon/TEAPO	10 μF,400 V	10 mm (Die.) × 12.5 mm (Hight)	Size,10 × 12.5 mm
35	2	C3 C5	Electrolytic Solid Capacitor	PCH477M6R3S1AGE08K	TEAPO	470 μF,6.3 V	6.3 mm (Die.) × 8mm (Hight)	Aluminum Solid Capacitor, size, $6.3 \times 8 \text{ mm}$

Table 2. BILL OF MATERIAL (continued)

References

 DON Semiconductor datasheet for <u>NCP1360/5</u> CC/CV primary side PWM current mode controller.

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